Analog Power AM2345PE

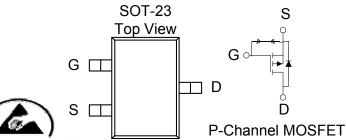
## P - Channel 40V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r <sub>DS(on)</sub> provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe SOT-23 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY					
$V_{DS}(V)$	$r_{DS(on)}(\Omega)$ $I_D(A)$				
-40	$0.164 @V_{CS} = -10 \text{ V}$	-3.2			
-40	$0.260 @V_{CS} = -4.5V$	-2.6			



ESD Protected 2000V

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Ratings	Units	
Drain-Source Voltage		$V_{DS}$	-40	V	
Gate-Source Voltage		$V_{GS}$	±20	V	
	$T_A=25^{\circ}C$	т	± 3.2		
Continuous Drain Current <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1D	± 2.7	A	
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	±10		
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	0.4	A	
D a	$T_A=25^{\circ}C$	D	1.25	W	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	rD	0.8	**	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C	

THERMAL RESISTANCE RATINGS				
Parameter		Symbol	Maximum	Units
M . I	t <= 5 sec	D	100	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State	$R_{THJA}$	150	C/W

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

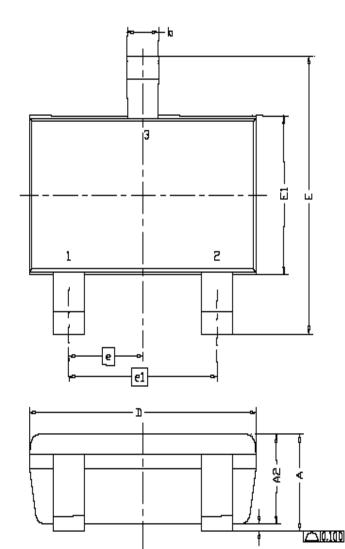
Downwoodow	Cumb - 1	T C P4*	Limits			TT •4
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Switch Off Characteristics						
Zara Cata Valtaga Dain Gurrant	т	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μА
Zero Cate Voltage Drain Current	Idss	$V_{DS} = -32 \text{ V}, V_{CS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			-10	
Gate-Body Leakage	IGSS	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±100	nA
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}, I_D = -250 \text{uA}$	-1.0			V
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-2			Α
Did O Di A	IDS(on)	$V_{GS} = -10 \text{ V}, I_D = -3.2 \text{ A}$			164	mΩ
Drain-Source On-Resistance <sup>A</sup>		$V_{GS}$ =-4.5 V, $I_D$ =-2.6 A			260	
Forward Tranconductance <sup>A</sup>	gs	$V_{DS}$ =-5 V, $I_D$ =-3.6 A		2		S
Diode Forward Voltage	Vsd	$I_S = -0.4  A, V_{GS} = 0  V$		-0.70		V
Dynamic <sup>b</sup>						
Total Gate Charge	Qg	103/3/ 53/		15		
Gate-Source Charge	Qgs	$V_{DS} = -10 \text{ V}, V_{GS} = -5 \text{ V},$ $I_{D} = -36 \text{ A}$		2.0		пC
Cate-Drain Charge	Qgd	ID3.0A		2.0		
Turn-On Delay Time	td(on)			10		
Rise Time	$t_{\rm r}$	$V_{DS} = -15 \text{ V}, I_D = -1 \text{ A},$		2.8		ns
Turn-Off Delay Time	td(off)	$R_G = 50 \Omega$ , $V_{GEN} = -10 V$		53.6		115
Fall-Time	$t_{\mathrm{f}}$			46		

## Notes

- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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## Package Information



пты	MILLIMETERS			
DIM,	MIN	NDM	MAX	
Α	0.935	0.95	1.10	
A1	0.01	-	0.10	
A2	0.85	0.90	0.925	
a	0.30	0.40	0.50	
C	0.10	0.15	0.25	
D	2.70	2.90	3.10	
Ε	2.60	2.80	3.00	
E1	1.40	1.60	1.80	
6	0.95 BSC			
el	1.90 BSC			
L	0.30	0.40	0.60	
L1	0.60REF			
LZ	0,25BSC			
R	0.10			
θ	Q*	4*	8*	
81	7"NOM			

